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Electronic Supplementary Information

Axially Chiral Bay-Tetraarylated Perylene Bisimide Dyes as Non-Fullerene

Acceptors in Organic Solar Cells

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1. Materials and Methods

All chemicals, reagents and solvents were purchased from commercial suppliers and purification if used after appropriate not stated otherwise. *N*,*N*′-di(2,6diisopropylphenyl)-1,6,7,12-tetrachloroperylene-3,4:9,10-bis(dicarboximides) and PBIs 1a-1e as well as 2b-5b were synthesized according to literature known procedures.^{S1,S2} Toluene used for synthesis was of HPLC grade and was dried prior to use utilizing a *Pure Solv MD 7* system from *Inert Technology*. Dichloromethane (DCM) was distilled prior to use. Column chromatography was performed using commercial glass columns packed with silica gel 60 M (particle size of 0.04 - 0.063 mm from Merck KGaA) stationary phase. Normal phase HPLC was performed on a JASCO recycling semipreparative HPLC system equipped with a VP 250/21 NUCLEOSIL 100-7 column from Macherey-Nagel. For chiral separation a *ReproSil 100 Chiral-NR 8 µm* column from Trentec (1a - 1e as well as 2b – 5b) or ReproSil Chiral-MIF 10 µm column from Dr. Maisch (2e attempted) was utilized.

UV/Vis/NIR spectroscopy was carried out at room temperature on a Jasco V770 spectrophotometer. Solution spectra were taken using 10 mm cuvettes (SUPRASIL[®], Hellma[®] Analytics, DCM spectroscopic grade). For thin-film spectra, the same spectrometer with an integration sphere was used. Neat films were prepared on quartz substrates (SUPRASIL[®], Hellma[®] Analytics) from a chloroform solution (spectroscopic grade). Spectra of blend films were taken using the respective thin-film device.

Fluorescence spectroscopy was carried out on a *FLS980* fluorescence spectrometer from Edinburgh Instruments. Spectra were corrected against the photomultiplier sensitivity and the lamp intensity. Fluorescence quantum yields were determined using the dilution method (OD < 0.05) and Oxazine 1 in ethanol with 11% as reference.^{S3}

Fluorescence lifetimes were determined with EPL picosecond pulsed diode lasers ($\lambda_{ex} = 560 \text{ nm}$) for time correlated single photon counting.

CD spectroscopy was carried out using a customised *JASCO CPL-300/J-1500* hybrid spectrometer.

NMR spectroscopy was performed using a Bruker Avance III HD 400 MHz NMR spectrometer relative to residual undeuterated solvent signals. Chemical shifts (δ) are listed in parts per million (ppm). The multiplicities for proton signals are abbreviated as *d* and *bm* for doublet and broad multiplet, respectively.

High resolution mass spectra were measured by electron spray ionization (**ESI**) using an *ESI microTOF Focus* mass spectrometer from Bruker Daltonics GmbH.

Melting points were determined using a SMP50 from *Stuart Equipment*.

Cyclic Voltammetry was measured on an *EC epsilon* (BASi instruments, UK) potentiostat connected with a three-electrode single-compartment cell. A platinum disc electrode was utilized as working electrode, a platinum wire as counter electrode and an Ag/AgCl electrode as reference electrode.

Single crystal X-ray diffraction was measured on a Bruker *D8 Quest Kappa* diffractometer with a Photon II CMOS detector and multi-layered mirror monochromated Cu_{Ka} radiation at 100 ± 1 K. The solved structures were obtained with Fourier techniques and the *Shelx* software package.^{S4} Crystallographic data are deposited on the Cambridge Crystallographic Data Centre as supplementary publication no. CCDC 2106434 (*Rac-1b*), CCDC 2106433 (*P-1b*), CCDC 2106436 (*Rac-1e*), CCDC 2106435 (*M-1e*) and CCDC 2106437 (*Rac-2e*).

AFM-Images were obtained by *NT-MDT Next Solver System* in semi contact mode by using a SCOUT 350 RAI (Nu Nano Ltd) silicon cantilever (spring constant = 42 N m^{-1} , resonance frequency = 350 kHz).

Organic thin-film devices (OSCs, SCLC) were prepared as organic solar cells in inverted bulk-heterojunction structure of ITO/ZnO/Blend/MoO₃/AI. SCLC-devices were fabricated in a structure of ITO/ZnO/Blend/BCP/AI (electron-mobility) or ITO/PEDOT:PSS/Blend/MoO₃/AI (hole mobility).

ITO-substrates (Soluxx GmbH) were cleaned with acetone (VWR, semiconductor grade), detergent, deionized water, and isopropanol (VWR, semiconductor grade) for 15 min each, followed by an ozone/UV treatment for 30 min.

The bottom layer was either ZnO or PEDOT:PSS. The ZnO-layer was deposited by static spin-casting ZnO nanoparticles^{S5} on top of the substrates (3000 rpm, 30 s) followed by thermal annealing (200 °C, 1 h). PEDOT:PSS (solids content: 1.3 - 1.7%, PEDOT:PSS 1:6 w/w, Heraeus) was deposited analogously by spin-casting with 2500 rpm for 60 s and thermally annealing at 150 °C for 10 min.

The donor-acceptor blends were prepared by stirring a **PCE-10** (1-Material Inc.) polymer solution overnight in chlorobenzene (CB). This solution was then given to the respective PBI and stirred for 4 h at room temperature under inert conditions followed by dynamic spin-casting at 1000 rpm for 60 s (MBraun Intergas Systeme GmbH, UNIIab Pro, $c(O_2) < 1$ ppm, $c(H_2O) < 1$ ppm).

For vaccum deposition, the substrates were placed in the evaporation system (OPTIvap-XL, Creaphys GmbH). As top layers, either MoO₃ or BCP (d = 10 nm, r = 0.07 - 0.15 Å s⁻¹, $p < 10^{-6}$ mbar, rotation = 10 rpm) were deposited followed by aluminium (d = 100 nm, r = 1 - 2 Å s⁻¹, $p < 10^{-6}$ mbar) using shadow masks.

The device area was 7.1 mm². J-V-characteristics were measured after calibration with

a standard silicon solar cell with a KG filter (ISE Freiburg) under an AM1.5G Oriel Sol3ATM Class AAA solar simulator (Newport[®]) by a parameter analyser (Botest Systems GmbH).

SCLC measurements were recorded and evaluated using the protocol of Blakesley *et al.*^{S6} applying Mott-Murgatroyd equation and a built-in-voltage of $V_{bi} = 0.6 \text{ V}$ (**PCE-10**, **1b**) and a relative permittivity of $\varepsilon = 3.5$. Active layer thickness was determined *via* AFM.

EQE measurements were carried out with a Quantum Efficiency/IPCE measurement kit (Newport[®]) by using a 300 W Xe-lamp and a Cornerstone monochromator with a Merlin Lock-In Amplifier for detection.

TD-DFT calculations were performed with GAUSSIAN 09 software^{S7} on wB97/def2SVP level of theory. Molecule coordinates were taken from respective single-crystal structures without further geometry optimization.

2. Synthesis



N,N'-di(2,6-diisopropylphenyl)-1,6,7,12-tetrachloroperylene-3,4:9,10bis(dicarboximide) (100 µmol), 2-naphthylboronic acid (2.00 mmol, 20 eq.), anhydrous potassium carbonate (145 mg, 1.05 mmol. 10.5 eq.) and tetrakis(triphenylphosphine)palladium (34.7 mg, 30.0 µmol, 0.3 eq.) were given in a Schlenk tube. Degassed toluene (3.2 mL), ethanol (0.6 mL) and water (1.6 mL) were added. The mixture was subjected to three freeze-pump-thaw cycles. After stirring for 26 h at 80 °C, the mixture was extracted with dichloromethane and washed three times with water. The organic phases were combined, and the solvent removed under reduced pressure. The crude product was purified by column chromatography (hexane:dichloromethane 3:7) and HPLC (hexane:dichloromethane 1:2) to obtain 45.5 mg (37.4 mmol, 37%) of **2e** as purple solid.

¹H-NMR (400 MHz, CD₂Cl₂, 293 K): δ = 8.54 – 6.68 (bm, 38H), 2.91 (bm, 4H), 1.26 (d, 12H), 1.16 (d, 12H);

¹³C-NMR (100 MHz, CD₂Cl₂, 293 K): δ = 164.4, 146.6, 143.2, 138.4, 134.9, 132.9, 132.6, 132.4, 131.7, 129.9, 128.5, 128.2, 127.9, 127.5, 127.0, 126.6, 124.5, 122.9, 29.5, 24.2;

HRMS (ESI-TOF, pos. mode, MeCN/CHCl₃): *m*/*z* calculated for C₈₈H₆₆N₂NaO₄⁺ [M+Na]⁺: 1237.4915, found 1237.4877; m.p. >390 °C.

UV/Vis (CD₂Cl₂): $\Lambda_{max} / nm (\epsilon / M^{-1} cm^{-1}) = 615 (23900), 536 (25300).$

Fluorescence (CD₂Cl₂, $\Lambda_{ex} = 600 \text{ nm}$): $\Lambda_{max} / \text{nm} (\phi_f / \%) = 670 (31)$,

 $\tau / \text{ ns} (\Lambda_{\text{ex}} = 560 \text{ nm})$: = 9.3.

m.p.: >390 °C.



3. UV/Vis/NIR and Fluorescence

Fig. S1 a) UV/Vis/NIR absorption spectra of **2e** and b) normalized emission spectra in DCM solution ($c_0 \approx 4 \cdot 10^{-6}$ M) at room temperature.



Fig. S2 *J-V* characteristics (upper figures) as well as *EQE* (middle figures) and UV/Vis/NIR absorption spectra (lower figures) of **PCE-10** based devices of **1a-1e** (left) as well as **2b-5b** and **2e** (right). The total blend concentration was 15 mg ml⁻¹ (16 mg ml⁻¹ for **2e**) in chlorobenzene (CB) for all devices. D:A ratio was 1:1 (1.0:1.1 for **2e**) and 2% of 1-Chloronaphthalene (CN) was used as solvent additive. The solar cells were fabricated and characterized under inert conditions and AM1.5 G irradiation.



Fig. S3 *J-V* characteristics (top) of best **1b** based OSC devices with inverted architecture of ITO/**PCE-10**:**1b**/MoO₃/AI without solvent additive (left) or with 2% of 1-Chloronaphthalene (CN, right). *EQE* and UV/Vis/NIR absorption spectra of respective devices (bottom). The solar cells were fabricated and characterized under inert conditions and AM1.5 G irradiation.

5.



Fig. S4 AFM-height images of all **PCE-10** based PBI blends used as OSC device corresponding to Fig. 2 and Table 1. Thin film devices were spin-coated on ITO/ZnO coated glass substrate at room temperature under inert conditions. 5 x 5 μ m².



Fig. S5 AFM-height images of **PCE-10** based PBI blends of *P/M/Rac-1b* used as OSC device corresponding to Fig. 4 and Table 2 (top) as well as neat films of *P-1b* and *P-1e* from a chloroform solution ($c = 10 \text{ mg ml}^{-1}$). Thin films were spin-coated on ITO/ ZnO coated glass substrate (blends) or quartz (neat films) at room temperature under inert conditions. 5 x 5 μ m².

6. X-Ray

	Rac-1b	Rac- 1e	Rac- 2e	<i>P-</i> 1b	<i>M</i> -1e
Empirical formula	$C_{57}H_{43}CI_{13}N_2O_4$	$C_{79}H_{68}CI_{12}N_2O_4$	$C_{100}H_{76}CI_{12}N_2O_4$	$C_{57}H_{43}CI_{12}N_2O_4$	$C_{76}H_{60}CI_{16}N_2O_4$
<i>M</i> empirical (g mol⁻¹)	926.28	1523.08	1440.52	888.08	1253.94
Wavelength (Å)	1.54178	1.54178	1.54178	1.54178	1.54178
Т (К)	100	100	100	100	100
Description of the					
crystal					
Color	Red	Red	Red	Red	Red
Habit	Needle	Needle	Needle	Needle	Needle
Crystal System	Triclinic	Triclinic	Monoclinic	Hexagonal	Monoclinic
Space group	$P\overline{1}$	$P\overline{1}$	P21/c	<i>P</i> 6₅22	P 2 ₁
Unit cell dimension					
a (Å)	12.4343(7)	12.5786(9)	15.5844(10)	19.1064(9)	14.0489(10)
b (Å)	12.6105(7)	16.3365(12)	29.7802(17)	19.1064(9)	13.8721(10)
<i>c</i> (Å)	16.4663(10)	18.8231(14)	17.1937(10)	44.020(2)	16.7450(12)
α (°)	101.657(3)	74.006(3)	90	90	90
β (°)	90.456(3)	87.132(3)	110.767(3)	90	109.392(3)
γ(°)	118.044(3)	87.033(3)	90	120	90
Volume (Å ³)	2215.9(2)	3710.7(5)	7461.3(8)	13916.8(15)	3078.3(4)
Ζ	2	2	4	12	2
$ ho_{\rm alc.}$ (g cm ⁻³)	1.388	1.363	1.282	1.272	1.353
F(000)	964	1573	3024	5561.3	1304
Range of θ (°)	2.760 – 72.452	2.443 – 72.498	2.986 - 72.624	2.670 – 72.141	2.797 – 72.567
Goodness of Fit	1.027	1.019	1.052	1.116	1.088
CCDC	2106434	2106436	2106437	2106433	2106435

 Table S1 X-ray structure characteristics for all tetraarylated PBI derivatives.



Fig. S6 a) Side view onto the unit cell of racemic PBI *rac-***1b** (left) along the double stranded chromophore alignment within its single crystal structure (ellipsoids are set to 50 % probability) as well as rotated side view (right). (b). Top view onto the chromophore slip-stack arrangement of one isolated double strand (top) as well as top view onto a pair of enantiomers within the same unit cell (bottom). c) Rotated side view onto the chromophores within their unit cell. PBI atropo-enantiomers are colored in blue (*P*) and red (*M*), respectively. The ellipsoids are set to 50 % probability (C: gray). Disorder of the imide residues, hydrogen atoms as well as solvent molecules are omitted for clarity. The distance between the planes of adjacent chromophores (black) and distances between the centroids of the perylene cores (green), as well as twist angle α (black) and slip angle Θ (red) between two chromophores are indicated as well.

Tab	le S2	Calcula	ated	l Coulo	mb coupl	ing be	etweer	n a <i>P-</i> 1	b atro	po-enant	tiomer	and its	adjacent	<i>M</i> - 1b cł	۱rom	ophores
in e	ither	<i>–a</i> -axis	or	c-axis	direction	(Ēig.	S6b)	within	their	racemic	single	crysta	structure	based	on	Kasha's
mol	ecula	r exciton	the	eory. ^{S8}												

rac-1b	<i>r</i> _{с-с} (Å)	μ _{eg} a (D)	α (°)	θ (°)	J _{coul} (cm⁻¹)
P / M-1b (-a-axis direction)	10.6	6.4	6.8	39.4	-140.2
P / M-1b (c-axis direction)	10.7	6.4	2.0	36.7	-156.9

a) The transition dipole moment μ_g was calculated from UV/Vis/NIR absorption in DCM solution.

7. CD Spectroscopy



Fig. S7 UV/Vis/NIR absorption spectra (dashed lines) and CD spectra (solid lines) of *P*- (blue) and *M*- (red) atropoenantiomers of **1b** (left) and **1e** (right). Spectra were taken in DCM solution (top) as well as spin coated neat film (center, from 10 mg ml⁻¹ CHCl₃ solution on quartz) and OSC device (bottom, 15 mg ml⁻¹ 1:1 **PCE-10**:PBI solution on ITO/ZnO).

8. SCLC



Fig. S8 *J-V* curves of PBI **1b** based SCLC devices including Mott-Murgatroyd fit. Electron only devices (EOD) and hole only devices (HOD) in structures of ITO/ZnO/**PCE-10**:PBI/BCP/AI (EOD) and ITO/PEDOT:PSS/**PCE-10**:PBI/MoO₃/AI (HOD) were fabricated and characterized under dark and inert conditions according to literature known procedure.^{S6}

Table S3 Extracted hole mobilities and electron mobilities of 1b based SCLC devices. Electron only devices (EOD)andholeonlydevices(HOD)instructureofITO/ZnO/PCE-10:PBI/BCP/AI(EOD)andITO/PEDOT:PSS/PCE-10:PBI/MoO₃/AI(HOD)were fabricated and characterized under dark and inert conditionsaccording to literature known procedure.S6

Acceptor	µ _{electron} ^[a] / cm² V ^{−1} s ^{−1}	μ _{hole^[a] / cm² V⁻¹ s⁻¹}	μ electron max / cm ² V ⁻¹ s ⁻¹	$\mu_{ m hole\ max}$ / cm ² V ⁻¹ s ⁻¹
<i>P</i> -1b	$8.9 \pm 0.3 \cdot 10^{-6}$	$1.4 \pm 0.1 \cdot 10^{-3}$	$9.4 \cdot 10^{-6}$	$1.5 \cdot 10^{-3}$
<i>M</i> -1b	$9.1 \pm 0.4 \cdot 10^{-6}$	$1.3 \pm 0.1 \cdot 10^{-4}$	$9.7 \cdot 10^{-6}$	$1.4 \cdot 10^{-3}$
rac-1b	$13.7 \pm 0.2 \cdot 10^{-6}$	$1.0 \pm 0.1 \cdot 10^{-4}$	$13.9 \cdot 10^{-6}$	$1.1 \cdot 10^{-3}$

[a] Average of at least five independent devices.

9. TD-DFT



Fig. S9 TD-DFT calculated UV/Vis (top) and CD spectra (bottom) of *P*-**1b** monomer (dashed lines) and dimer (solid lines) using molecular geometry obtained from single crystal X-ray structure analysis. For monomer calculation, the bottom chromophore of the dimer entity with the lower twist angle of 32.4° was used (see inset or Fig.5). Calculations were performed on wB97/def2SVP level of theory and transition energies were shifted by 0.69 eV.

Transition	% Character	Wavelength (nm)	Oscillator strength
212 → 213	100	449.64	0.4395
194 → 213	2.9		
$204 \rightarrow 213$	4.3		
210 → 213	78.9	333.15	0.0534
211 → 214	5.6		
212 → 217	8.3		
197 → 213	6.5		
202 → 213	3.2		
210 → 214	8.7	326.12	0.2503
211 → 213	10.2		
212 → 216	11.4		
204 → 213	63.2		
210 → 213	2.7	305.04	0.0176
212 → 215	31.1		
203 → 213	17.0		
205 → 213	10.8	288.32	0.0105
<u>212 → 214</u>	72.1		
195 → 215	3.1		
197 → 213	11.0		
$198 \rightarrow 214$	30.0	275.62	0.0032
$198 \rightarrow 228$	4.3		
199 → 213	45.5		
199 → 219	6.2		
$195 \rightarrow 224$	2.5		
$190 \rightarrow 215$	2.7		
$197 \rightarrow 214$	0.0 50.7		
$190 \rightarrow 213$ $108 \rightarrow 210$	52.7 8 0	275.62	0.0003
$190 \rightarrow 219$ $108 \rightarrow 227$	0.0		
$190 \rightarrow 227$ $199 \rightarrow 214$	21.3		
$199 \rightarrow 228$	29		
$203 \rightarrow 213$	32		
$203 \rightarrow 216$	27		
204 → 213	3.2		
205 → 216	2.4	000.47	0.0700
210 → 214	7.8	266.17	0.0780
210 → 229	2.4		
212 → 215	7.7		
212 → 227	70.6		
205 → 213	5.0		
219 → 213	83.2	262.97	0.0012
211 → 215	7.3	203.07	0.0012
212 → 224	4.6		
204 → 213	9.6		
205 → 216	4.9		
210 → 214	7.2	263.06	0.6960
210 → 229	7.0	200.00	0.0000
$212 \rightarrow 215$	31.7		
212 → 227	39.5		

Table S4 Calculated UV/Vis/NIR transitions for monomeric *P*-1b (topmost molecule of the dimeric entity) obtained from its single crystal structure.

Transition	% Character	Wavelength (nm)	Oscillator strength
423 → 425	18.4		
$424 \rightarrow 425$	23.9	472.83	0.2182
$212 \rightarrow 426$	60.2		
423 → 425	58.9		
$423 \rightarrow 426$	22.0		
$424 \rightarrow 425$	97	451.64	0.3446
$424 \rightarrow 426$	9.4		
<u>419</u> → 425	2.6		
$410 \rightarrow 420$	14.7		
$421 \rightarrow 428$	3.4		
$421 \rightarrow 420$	28.0	342.65	0.0547
$422 \rightarrow 425$	20.5		
$422 \rightarrow 420$	45.4		
$424 \rightarrow 434$	5.0		
$419 \rightarrow 425$	42.3		
$419 \rightarrow 426$	9.1		0.00/0
$422 \rightarrow 425$	24.7	336.21	0.0812
$422 \rightarrow 426$	17.0		
$423 \rightarrow 433$	6.9		
420 → 426	14.5		
421 → 425	20.8		
421 → 426	37.0		
422 → 428	5.0	332.86	0 1447
$424 \rightarrow 425$	7.7	332.00	0.1447
$224 \rightarrow 426$	3.6		
$224 \rightarrow 431$	5.5		
$224 \rightarrow 232$	6.0		
$393 \rightarrow 425$	3.2		
419 → 427	3.2		
$420 \rightarrow 425$	25.9		
$420 \rightarrow 426$	8.4		
421 → 425	25.3		
221 → 426	9.0	328.89	0.1444
222 → 427	3.0		
223 → 231	5.1		
223 → 232	4.5		
224 → 225	8.3		
224 → 226	3.2		
420 → 225	6.8		
421 → 226	6.3		
$424 \rightarrow 225$	58.7	324.80	0.0882
$424 \rightarrow 426$	28.2		
$223 \rightarrow 425$	23.5		
$223 \rightarrow 426$	76.5	312.12	0.0248
$401 \rightarrow 425$	3.2		
401 → 426	10.8		
407 - 426	3 0		
$409 \rightarrow 420$	3.8		
$400 \rightarrow 420$	10.0		
$400 \rightarrow 420$	7 1		
$410 \rightarrow 420$	69	310.16	0.0076
$410 \rightarrow 420$	6.4		
412 426	10.5		
$412 \rightarrow 420$	10:5		
$\frac{1}{224} \rightarrow 221$	2.0 14 0		
$424 \rightarrow 225$	20.4		
$424 \rightarrow 430$	20.4		
$401 \rightarrow 425$	5.3		
$404 \rightarrow 425$	17.0		
$404 \rightarrow 420$	5.9		
$407 \rightarrow 425$	0.0		
$410 \rightarrow 425$	12.4	200.00	0.0000
$410 \rightarrow 426$	8.2	306.80	0.0228
$412 \rightarrow 426$	2.8		
$414 \rightarrow 425$	5.1		
$423 \rightarrow 427$	3.2		
423 → 229	23.4		
$423 \rightarrow 230$	10.1		

Table S5 Calculated UV/Vis/NIR transitions for dimeric P-1b obtained from its single crystal structure.

10. Cyclic Voltammetry



Fig. S10 Cyclic voltammograms (solid lines) as well as square wave voltammograms (dashed lines) of PBI **2e** in DCM solution ($c_0 \approx 2 \cdot 10^{-4}$ M) at 293 K using tetrabutylammonium hexafluorophosphat (TBAHFP 0.1 M) as electrolyte. The scanning speed was 100 mV s⁻¹.

Table S6 Redox properties of 2e. Half-wave potentials were determined by square wave voltammetry measured in DCM (0.1 M TBAHFP) vs. Fc⁺/Fc at room temperature.

PBI	E _{red1}	E _{red2}	E _{ox1}	Е _{номо^[а]}	E _{LUMO^[a]}	E _{gap}
	(V)	(V)	(V)	(eV)	(eV)	(eV)
2e	-1.00	-1.23	0.98	-6.13	-4.15	1.98

[a] Calculated according to literature known procedure using the experimentally determined redox potentials $(E_{HOMO} = -[E_{ox1} + 5.15 \text{ eV}] \text{ and } E_{LUMO} = -[E_{red1} + 5.15 \text{ eV}])$ and the energy level of Fc+/Fc with respect to the vacuum level (-5.15 eV).^{S9}

11. NMR Spectra



12. References

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